

# TS3A24159 0.3-Ω 2-channel SPDT Bidirectional Analog Switch

## Dual-channel 2:1 Multiplexer and Demultiplexer

### 1 Features

- Specified break-before-make switching
- Low ON-state resistance (0.3 Ω max)
- Low charge injection
- Excellent ON-state resistance matching
- Low total harmonic distortion (THD)
- 1.65-V to 3.6-V Single-supply operation
- Control inputs are 1.8-V logic compatible
- Latch-up performance exceeds 100 mA per JESD 78, class II
- ESD Performance tested per JESD 22
  - 2000-V Human-body model (A114-B, Class II)
  - 1000-V Charged-device model (C101)

### 2 Applications

- Cell phones
- Personal digital assistant (PDAs)
- Portable instrumentation
- Audio and video signal routing
- Low-voltage data-acquisition systems
- Communication circuits
- Modems
- Hard drives
- Computer peripherals
- Wireless terminals and peripherals

### 3 Description

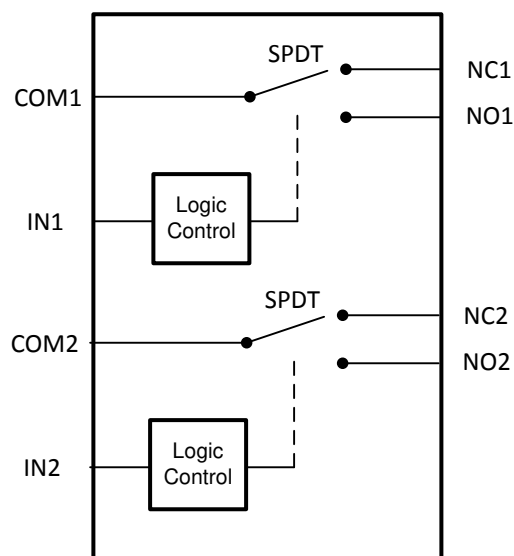
The TS3A24159 is a 2-channel single-pole double-throw (SPDT) bidirectional analog switch that is designed to operate from 1.65 V to 3.6 V. It offers low ON-state resistance and excellent ON-state resistance matching with the break-before-make feature, to prevent signal distortion during the transferring of a signal from one channel to another. The device has excellent total harmonic distortion (THD) performance, low ON-state resistance, and consumes very low power. These are some of the features that make this device suitable for a variety of markets and many different applications.

**Device Information<sup>(1)</sup>**

PART NUMBER	PACKAGE	BODY SIZE (NOM)
TS3A24159	VSSOP (10)	3.00 mm × 3.00 mm
	VSON (10)	3.00 mm × 3.00 mm
	DSBGA (10)	1.86 mm × 1.35 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

**Functional Block Diagram**



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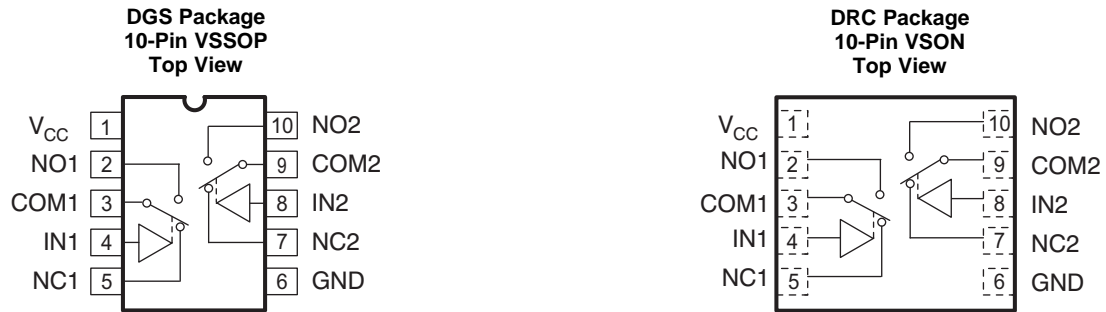
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## 4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

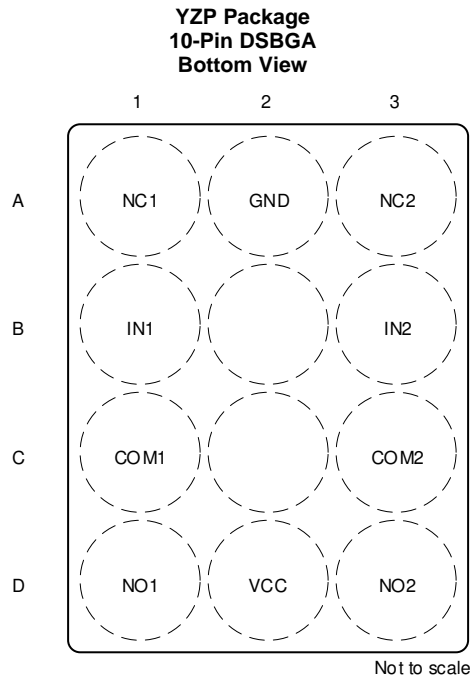
Changes from Revision E (March 2019) to Revision F	Page
• Changed the YZP package image view From: Top-Through View To: Bottom View .....	4
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• Changed the YZP Package image and deleted the <i>YZP Package Terminal Assignments</i> table .....	4
• Changed Turnon time $V_{CC}$ (Full) value From: 2.3 V to 2.7 V To: 2.7 V to 3.6 V in <i>Switching Characteristics for a 3-V Supply</i> .....	10
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Changes from Revision C (February 2008) to Revision D	Page
• Added <i>Pin Configuration and Functions</i> section, <i>ESD Ratings</i> table, <i>Feature Description</i> section, <i>Device Functional Modes</i> , <i>Application and Implementation</i> section, <i>Power Supply Recommendations</i> section, <i>Layout</i> section, <i>Device and Documentation Support</i> section, and <i>Mechanical, Packaging, and Orderable Information</i> section .....	1
• Changed $V+$ to $V_{CC}$ throughout the document to meet JEDEC standards .....	1

## 5 Pin Configuration and Functions



**Pin Functions - VSSOP and VSON**

PIN		I/O	DESCRIPTION
NO.	NAME		
1	V <sub>CC</sub>	—	Power Supply
2	NO1	I/O	Normally Open Signal Path
3	COM1	I/O	Common Signal Path
4	IN1	I	Digital Control to Connect COM to NO or NC
5	NC1	I/O	Normally Closed Signal Path
6	GND	—	Ground
7	NC2	I/O	Normally Closed Signal Path
8	IN2	I	Digital Control to Connect COM to NO or NC
9	COM2	I/O	Common Signal Path
10	NO2	I/O	Normally Open Signal Path



### Pin Functions - DSBGA

PIN		I/O	DESCRIPTION
NO.	NAME		
A1	NC1	I/O	Normally Closed Signal Path
A2	GND	—	Ground
A3	NC2	I/O	Normally Closed Signal Path
B1	IN1	I	Digital Control to Connect COM to NO or NC
B3	IN2	I	Digital Control to Connect COM to NO or NC
C1	COM1	I/O	Common Signal Path
C3	COM2	I/O	Common Signal Path
D1	NO1	I/O	Normally Open Signal Path
D2	V <sub>CC</sub>	—	Power Supply
D3	NO2	I/O	Normally Open Signal Path

## 6 Specifications

### 6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) <sup>(1)</sup> <sup>(2)</sup>

			MIN	MAX	UNIT
$V_{CC}$	Supply voltage <sup>(3)</sup>		−0.5	3.6	V
$V_{NC}$ $V_{NO}$ $V_{COM}$	Signal voltage <sup>(3)(4)</sup>		−0.5	$V_{CC} + 0.5$	V
$I_{I/O}$	Analog port diode current	$V_{NC}, V_{NO}, V_{COM} < 0$	−50	50	mA
$I_{NC}$ $I_{NO}$ $I_{COM}$	ON-state switch current ON-state peak switch current <sup>(5)</sup>	$V_{NC}, V_{NO}, V_{COM} = 0$ to $V_{CC}$	−300 −500	300 500	mA
$V_{IN}$	Digital input voltage		−0.5	3.6	V
$I_{IK}$	Digital input clamp current <sup>(3)</sup>	$V_I < 0$	−50		mA
$I_{CC}$	Continuous current through $V_{CC}$			100	mA
$I_{GND}$	Continuous current through GND		−100		mA
$T_{stg}$	Storage temperature		−65	150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum
- (3) All voltages are with respect to ground, unless otherwise specified.
- (4) This value is limited to 5.5 V maximum.
- (5) Pulse at 1-ms duration <10% duty cycle

### 6.2 ESD Ratings

		VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	2000	V
	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>		
	Charged-device model (CDM), per JEDEC specification JESD22-C101 or ANSI/ESDA/JEDEC JS-002 <sup>(2)</sup>	1000	

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

### 6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
$V_{CC}$	Supply Voltage	1.65	3.6	V
$V_{NC}$ $V_{NO}$ $V_{COM}$	Signal Voltage	0	$V_{CC}$	V
$V_{IN}$	Digital Input Voltage	0	$V_{CC}$	V

## 6.4 Thermal Information

THERMAL METRIC <sup>(1)</sup>		TS3A24159			UNIT
		DGS (VSSOP)	DRC (VSON)	YZP (DSBGA)	
		10 PINS	10 PINS	10 PINS	
R <sub>θJA</sub>	Junction-to-ambient thermal resistance	154	49.4	90.9	°C/W
R <sub>θJC(top)</sub>	Junction-to-case (top) thermal resistance	37.9	71.2	0.3	°C/W
R <sub>θJB</sub>	Junction-to-board thermal resistance	83.6	23.8	8.3	°C/W
ψ <sub>JT</sub>	Junction-to-top characterization parameter	1.4	2.2	3.2	°C/W
ψ <sub>JB</sub>	Junction-to-board characterization parameter	82.2	23.8	8.3	°C/W
R <sub>θJC(bot)</sub>	Junction-to-case (bottom) thermal resistance	N/A	6.1	N/A	°C/W

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

## 6.5 Electrical Characteristics for 3-V Supply

V<sub>CC</sub> = 2.7 V to 3.6 V, T<sub>A</sub> = –40°C to 85°C (unless otherwise noted) <sup>(1)</sup>

PARAMETER	TEST CONDITIONS	T <sub>A</sub>	V <sub>CC</sub>	MIN	TYP	MAX	UNIT
<b>ANALOG SWITCH</b>							
Analog signal range	V <sub>COM</sub> , V <sub>NO</sub> , V <sub>NC</sub>			0		V <sub>CC</sub>	V
Peak ON resistance	r <sub>peak</sub>	0 ≤ (V <sub>NO</sub> or V <sub>NC</sub> ) ≤ V <sub>CC</sub> , I <sub>COM</sub> = –100 mA, Switch ON, See Figure 10	25°C Full	2.7 V	0.2	0.3 0.35	Ω
ON-state resistance	r <sub>on</sub>	V <sub>NO</sub> or V <sub>NC</sub> = 2 V, I <sub>COM</sub> = –100 mA, Switch ON, See Figure 10	25°C Full	2.7 V	0.26	0.3 0.34	Ω
ON-state resistance match between channels	Δr <sub>on</sub>	V <sub>NO</sub> or V <sub>NC</sub> = 2 V, 0.8 V, I <sub>COM</sub> = –100 mA, Switch ON, See Figure 10	25°C Full	2.7 V	0.01	0.05 0.05	Ω
ON-state resistance flatness	r <sub>on(flat)</sub>	0 ≤ (V <sub>NO</sub> or V <sub>NC</sub> ) ≤ V <sub>CC</sub> , I <sub>COM</sub> = –100 mA, Switch ON, See Figure 10	25°C	2.7 V	0.13		Ω
		V <sub>NO</sub> or V <sub>NC</sub> = 2 V, 0.8 V, I <sub>COM</sub> = –100 mA, Switch ON, See Figure 10	25°C Full	2.7 V	0.01	0.04 0.05	Ω
NC, NO OFF leakage current	I <sub>NC(OFF)</sub> , I <sub>NO(OFF)</sub>	V <sub>NC</sub> or V <sub>NO</sub> = 1 V, V <sub>COM</sub> = 3 V, or V <sub>NC</sub> or V <sub>NO</sub> = 3 V, V <sub>COM</sub> = 1 V, Switch OFF, See Figure 11	25°C Full	3.6 V	–10	10 50	nA
NC, NO ON leakage current	I <sub>NC(ON)</sub> , I <sub>NO(ON)</sub>	V <sub>NC</sub> or V <sub>NO</sub> = 1 V, V <sub>COM</sub> = Open, or V <sub>NC</sub> or V <sub>NO</sub> = 3 V, V <sub>COM</sub> = Open, Switch ON, See Figure 12	25°C Full	3.6 V	–10	10 100	nA
COM ON leakage current	I <sub>COM(ON)</sub>	V <sub>NC</sub> or V <sub>NO</sub> = Open, V <sub>COM</sub> = 1 V, or V <sub>NC</sub> or V <sub>NO</sub> = Open, V <sub>COM</sub> = 3 V, Switch ON, See Figure 12	25°C Full	3.6 V	–10	10 100	nA
<b>DIGITAL CONTROL INPUTS (IN1, IN2)<sup>(2)</sup></b>							
Input logic high	V <sub>IH</sub>		Full		1.4		V
Input logic low	V <sub>IL</sub>		Full			0.5	V
Input leakage current	I <sub>IH</sub> , I <sub>IL</sub>	V <sub>I</sub> = 3.6 V or 0	25°C Full	3.6 V	–40	5 40 50	nA

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

(2) All unused digital inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number [SCBA004](#).

## Electrical Characteristics for 3-V Supply (continued)

 $V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$ ,  $T_A = -40^\circ\text{C to } 85^\circ\text{C}$  (unless otherwise noted) <sup>(1)</sup>

PARAMETER	TEST CONDITIONS	$T_A$	$V_{CC}$	MIN	TYP	MAX	UNIT
<b>DYNAMIC</b>							
Charge injection	$Q_C$	$V_{GEN} = 0$ , $R_{GEN} = 0$ , $C_L = 1 \text{ nF}$ , See Figure 19	25°C	3 V	9		pC
NC, NO OFF capacitance	$C_{NC(OFF)}$ , $C_{NO(OFF)}$	$V_{NC}$ or $V_{NO} = V_{CC}$ or GND, Switch OFF,	See Figure 13	25°C	3 V	90	pF
NC, NO ON capacitance	$C_{NC(ON)}$ , $C_{NO(ON)}$	$V_{NC}$ or $V_{NO} = V_{CC}$ or GND, Switch ON,	See Figure 13	25°C	3 V	224	pF
COM ON capacitance	$C_{COM(ON)}$	$V_{COM} = V_{CC}$ or GND, Switch ON,	See Figure 13	25°C	3 V	250	pF
Digital input capacitance	$C_I$	$V_{IN} = V_{CC}$ or GND,	See Figure 13	25°C	3 V	2	pF
Bandwidth	BW	$R_L = 50 \Omega$ , Switch ON,	See Figure 16	25°C	3 V	23	MHz
OFF isolation	$O_{ISO}$	$R_L = 50 \Omega$ , $f = 1 \text{ MHz}$ ,	See Figure 17	25°C	3 V	-72	dB
Crosstalk	$X_{TALK}$	$R_L = 50 \Omega$ , $f = 1 \text{ MHz}$ ,	See Figure 18	25°C	3 V	-96	dB
Total harmonic distortion	THD	$R_L = 600 \Omega$ , $C_L = 50 \text{ pF}$ , $f = 20 \text{ Hz to } 20 \text{ kHz}$ , See Figure 20	25°C	3 V	0.003%		
<b>SUPPLY</b>							
Positive supply current	$I_{CC}$	$V_{IN} = V_{CC}$ or GND	25°C	3.6 V	15	100	nA
			Full		1		μA

## 6.6 Electrical Characteristics for 2.5-V Supply

 $V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$ ,  $T_A = -40^\circ\text{C to } 85^\circ\text{C}$  (unless otherwise noted) <sup>(1)</sup>

PARAMETER	TEST CONDITIONS	$T_A$	$V_{CC}$	MIN	TYP	MAX	UNIT
<b>ANALOG SWITCH</b>							
Analog signal range	$V_{COM}$ , $V_{NO}$ , $V_{NC}$			0		$V_{CC}$	V
Peak ON resistance	$r_{peak}$	$0 \leq (V_{NO} \text{ or } V_{NC}) \leq V_{CC}$ , $I_{COM} = -8 \text{ mA}$ , Switch ON, See Figure 10	25°C Full	2.3 V	0.35 0.45		Ω
ON-state resistance	$r_{on}$	$V_{NO}$ or $V_{NC} = 1.8 \text{ V}$ , $I_{COM} = -8 \text{ mA}$ , Switch ON, See Figure 10	25°C Full	2.3 V		0.4	Ω
ON-state resistance match between channels	$\Delta r_{on}$	$V_{NO}$ or $V_{NC} = 1.8 \text{ V}$ , $0.8 \text{ V}$ , $I_{COM} = -8 \text{ mA}$ , Switch ON, See Figure 10	25°C Full	2.3 V	0.01 0.05	0.05 0.05	Ω
ON-state resistance flatness	$r_{on(Flat)}$	$0 \leq (V_{NO} \text{ or } V_{NC}) \leq V_{CC}$ , $I_{COM} = -8 \text{ mA}$ , Switch ON, See Figure 10	25°C	2.3 V	0.05		Ω
		$V_{NO}$ or $V_{NC} = 0.8 \text{ V}$ , $1.8 \text{ V}$ , $I_{COM} = -8 \text{ mA}$ , Switch ON, See Figure 10	25°C		0.03	0.08	
			Full			0.1	
NC, NO OFF leakage current	$I_{NC(OFF)}$ , $I_{NO(OFF)}$	$V_{NC}$ or $V_{NO} = 0.5 \text{ V}$ , $V_{COM} = 2.2 \text{ V}$ , or $V_{NC}$ or $V_{NO} = 2.2 \text{ V}$ , $V_{COM} = 0.5 \text{ V}$ , Switch OFF, See Figure 11	25°C Full	2.7 V	-10 -50	10 50	nA
NC, NO ON leakage current	$I_{NC(ON)}$ , $I_{NO(ON)}$	$V_{NC}$ or $V_{NO} = 0.5 \text{ V}$ , $V_{COM} = \text{Open}$ , or $V_{NC}$ or $V_{NO} = 2.2 \text{ V}$ , $V_{COM} = \text{Open}$ , Switch ON, See Figure 12	25°C Full	2.7 V	-10 -100	10 100	nA

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum.

## Electrical Characteristics for 2.5-V Supply (continued)

 $V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$ ,  $T_A = -40^\circ\text{C to } 85^\circ\text{C}$  (unless otherwise noted) <sup>(1)</sup>

PARAMETER	TEST CONDITIONS	$T_A$	$V_{CC}$	MIN	TYP	MAX	UNIT
<b>ANALOG SWITCH (continued)</b>							
COM ON leakage current	$I_{COM(ON)}$	$V_{NC}$ or $V_{NO} = \text{Open}$ , $V_{COM} = 0.5 \text{ V}$ , or $V_{NC}$ or $V_{NO} = \text{Open}$ , $V_{COM} = 2.2 \text{ V}$ , Switch ON, See <a href="#">Figure 12</a>	25°C Full	2.7 V	-10 -100	10 100	nA
<b>DIGITAL CONTROL INPUTS (IN1, IN2)<sup>(2)</sup></b>							
Input logic high	$V_{IH}$	Full		1.25			V
Input logic low	$V_{IL}$	Full				0.5	V
Input leakage current	$I_{IH}$ , $I_{IL}$	25°C Full	2.7 V	-40 -50	5	40 50	nA
<b>DYNAMIC</b>							
Charge injection	$Q_C$	$V_{GEN} = 0$ , $R_{GEN} = 0$ , $C_L = 1 \text{ nF}$ , See <a href="#">Figure 19</a>	25°C	2.5 V	8		pC
NC, NO OFF capacitance	$C_{NC(OFF)}$ , $C_{NO(OFF)}$	$V_{NC}$ or $V_{NO} = V_{CC}$ or GND, Switch OFF, See <a href="#">Figure 13</a>	25°C	2.5 V	90		pF
NC, NO ON capacitance	$C_{NC(ON)}$ , $C_{NO(ON)}$	$V_{NC}$ or $V_{NO} = V_{CC}$ or GND, Switch ON, See <a href="#">Figure 13</a>	25°C	2.5 V	250		pF
COM ON capacitance	$C_{COM(ON)}$	$V_{COM} = V_{CC}$ or GND, Switch ON, See <a href="#">Figure 13</a>	25°C	2.5 V	250		pF
Digital input capacitance	$C_i$	$V_i = V_{CC}$ or GND, See <a href="#">Figure 13</a>	25°C	2.5 V	2		pF
Bandwidth	BW	$R_L = 50 \Omega$ , Switch ON, See <a href="#">Figure 16</a>	25°C	2.5 V	23		MHz
OFF isolation	$O_{ISO}$	$R_L = 50 \Omega$ , $f = 1 \text{ MHz}$ , See <a href="#">Figure 17</a>	25°C	2.5 V	-72		dB
Crosstalk	$X_{TALK}$	$R_L = 50 \Omega$ , $f = 1 \text{ MHz}$ , See <a href="#">Figure 18</a>	25°C	2.5 V	-96		dB
Total harmonic distortion	THD	$R_L = 600 \Omega$ , $C_L = 50 \text{ pF}$ , $f = 20 \text{ Hz to } 20 \text{ kHz}$ , See <a href="#">Figure 20</a>	25°C	2.5 V	0.003%		
<b>SUPPLY</b>							
Positive supply current	$I_{CC}$	$V_i = V_{CC}$ or GND	25°C Full	2.7 V	10 700	100	nA

(2) All unused digital inputs of the device must be held at  $V_{CC}$  or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number [SCBA004](#).

## 6.7 Electrical Characteristics for 1.8-V Supply

 $V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$ ,  $T_A = -40^\circ\text{C to } 85^\circ\text{C}$  (unless otherwise noted) <sup>(1)</sup>

PARAMETER	TEST CONDITIONS	$T_A$	$V_{CC}$	MIN	TYP	MAX	UNIT
<b>ANALOG SWITCH</b>							
Analog signal range	$V_{COM}$ , $V_{NO}$ , $V_{NC}$			0		$V_{CC}$	V
Peak ON resistance	$r_{peak}$	$0 \leq (V_{NO} \text{ or } V_{NC}) \leq V_{CC}$ , $I_{COM} = -2 \text{ mA}$ , Switch ON, See <a href="#">Figure 10</a>	25°C Full	1.65 V	0.4 0.8	0.7	$\Omega$
ON-state resistance	$r_{on}$	$V_{NO}$ or $V_{NC} = 1.5 \text{ V}$ , $I_{COM} = -2 \text{ mA}$ , Switch ON, See <a href="#">Figure 10</a>	25°C Full	1.65 V	0.3 0.5	0.45	$\Omega$

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum



## Electrical Characteristics for 1.8-V Supply (continued)

 $V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$ ,  $T_A = -40^\circ\text{C to } 85^\circ\text{C}$  (unless otherwise noted) <sup>(1)</sup>

PARAMETER	TEST CONDITIONS	$T_A$	$V_{CC}$	MIN	TYP	MAX	UNIT
<b>ANALOG SWITCH (continued)</b>							
ON-state resistance match between channels $\Delta r_{on}$	$V_{NO}$ or $V_{NC} = 0.6 \text{ V}$ , $1.5 \text{ V}$ , $I_{COM} = -2 \text{ mA}$ , Switch ON, See <a href="#">Figure 10</a>	25°C Full	1.65 V	0.02	0.04	0.05	$\Omega$
ON-state resistance flatness $r_{on(flat)}$	$0 \leq (V_{NO} \text{ or } V_{NC}) \leq V_{CC}$ , $I_{COM} = -2 \text{ mA}$ , Switch ON, See <a href="#">Figure 10</a>	25°C	1.65 V	0.13			$\Omega$
	$V_{NO}$ or $V_{NC} = 0.6 \text{ V}$ , $1.5 \text{ V}$ , $I_{COM} = -8 \text{ mA}$ , Switch ON, See <a href="#">Figure 10</a>	25°C Full		0.08	0.15	0.2	
NC, NO OFF leakage current $I_{NC(OFF)}$ , $I_{NO(OFF)}$	$V_{NC}$ or $V_{NO} = 0.3 \text{ V}$ , $V_{COM} = 1.65 \text{ V}$ , or $V_{NC}$ or $V_{NO} = 1.65 \text{ V}$ , $V_{COM} = 0.3 \text{ V}$ , Switch OFF, See <a href="#">Figure 11</a>	25°C Full	1.95	-10		10	nA
				-50		50	
NC, NO ON leakage current $I_{NC(ON)}$ , $I_{NO(ON)}$	$V_{NC}$ or $V_{NO} = 0.3 \text{ V}$ , $V_{COM} = \text{Open}$ , or $V_{NC}$ or $V_{NO} = 1.65 \text{ V}$ , $V_{COM} = \text{Open}$ , Switch ON, See <a href="#">Figure 12</a>	25°C Full	1.95 V	-10		10	nA
				-100		100	
COM ON leakage current $I_{COM(ON)}$	$V_{NC}$ or $V_{NO} = \text{Open}$ , $V_{COM} = 0.3 \text{ V}$ , or $V_{NC}$ or $V_{NO} = \text{Open}$ , $V_{COM} = 1.65 \text{ V}$ , Switch ON, See <a href="#">Figure 12</a>	25°C Full	1.95 V	-10		10	nA
				-100		100	
<b>DIGITAL CONTROL INPUTS (IN1, IN2)<sup>(2)</sup></b>							
Input logic high $V_{IH}$		Full		1			V
Input logic low $V_{IL}$		Full				0.4	V
Input leakage current $I_{IH}$ , $I_{IL}$	$V_I = 1.95 \text{ V or } 0$	25°C Full	1.95 V	-40	5	40	nA
				-50		50	
<b>DYNAMIC</b>							
Charge injection $Q_C$	$V_{GEN} = 0$ , $R_{GEN} = 0$ , $C_L = 1 \text{ nF}$ , See <a href="#">Figure 19</a>	25°C	1.8 V		5		pC
NC, NO OFF capacitance $C_{NC(OFF)}$ , $C_{NO(OFF)}$	$V_{NC}$ or $V_{NO} = V_{CC}$ or GND, Switch OFF, See <a href="#">Figure 13</a>	25°C	1.8 V		90		pF
NC, NO ON capacitance $C_{NC(ON)}$ , $C_{NO(ON)}$	$V_{NC}$ or $V_{NO} = V_{CC}$ or GND, Switch ON, See <a href="#">Figure 13</a>	25°C	1.8 V		250		pF
COM ON capacitance $C_{COM(ON)}$	$V_{COM} = V_{CC}$ or GND, Switch ON, See <a href="#">Figure 13</a>	25°C	1.8 V		250		pF
Digital input capacitance $C_{IN}$	$V_I = V_{CC}$ or GND, See <a href="#">Figure 13</a>	25°C	1.8 V		2		pF
Bandwidth $BW$	$R_L = 50 \Omega$ , Switch ON, See <a href="#">Figure 16</a>	25°C	1.8 V		23		MHz
OFF isolation $O_{ISO}$	$R_L = 50 \Omega$ , $f = 1 \text{ MHz}$ , See <a href="#">Figure 17</a>	25°C	1.8 V		-73		dB
Crosstalk $X_{TALK}$	$R_L = 50 \Omega$ , $f = 1 \text{ MHz}$ , See <a href="#">Figure 18</a>	25°C	1.8 V		-97		dB
Total harmonic distortion $THD$	$R_L = 600 \Omega$ , $C_L = 50 \text{ pF}$ , $f = 20 \text{ Hz to } 20 \text{ kHz}$ , See <a href="#">Figure 20</a>	25°C	1.8 V		0.005%		
<b>SUPPLY</b>							
Positive supply current $I_{CC}$	$V_I = V_{CC}$ or GND	25°C Full	1.95 V		100	50	nA
						700	

(2) All unused digital inputs of the device must be held at VCC or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number [SCBA004](#).

## 6.8 Switching Characteristics for a 3-V Supply

 $V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$ ,  $T_A = -40^\circ\text{C to } 85^\circ\text{C}$  (unless otherwise noted) <sup>(1)</sup>

PARAMETER	TEST CONDITIONS	$T_A$	$V_{CC}$	MIN	TYP	MAX	UNIT
<b>Dynamic</b>							
Turnon time	$t_{ON}$	$V_{COM} = V_{CC}$ , $R_L = 50 \Omega$	$C_L = 35 \text{ pF}$ , See <a href="#">Figure 14</a>	25°C	3.0 V	20 35	ns
				Full	2.7 V to 3.6 V	40	
Turnoff time	$t_{OFF}$	$V_{COM} = V_{CC}$ , $R_L = 50 \Omega$	$C_L = 35 \text{ pF}$ , See <a href="#">Figure 14</a>	25°C	3.0 V	12 25	ns
				Full	2.7 V to 3.6 V	30	
Break-before-make time	$t_{BBM}$	$V_{NC} = V_{NO} = V_{CC}$ , $R_L = 50 \Omega$	$C_L = 35 \text{ pF}$ , See <a href="#">Figure 15</a>	25°C	3.0 V	1 10 25	ns
				Full	2.7 V to 3.6 V	0.5 30	

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

## 6.9 Switching Characteristics for a 2.5-V Supply

 $V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$ ,  $T_A = -40^\circ\text{C to } 85^\circ\text{C}$  (unless otherwise noted) <sup>(1)</sup>

PARAMETER	TEST CONDITIONS	$T_A$	$V_{CC}$	MIN	TYP	MAX	UNIT
<b>Dynamic</b>							
Turnon time	$t_{ON}$	$V_{COM} = V_{CC}$ , $R_L = 50 \Omega$	$C_L = 35 \text{ pF}$ , See <a href="#">Figure 14</a>	25°C	2.5 V	23 45	ns
				Full	2.3 V to 2.7 V	50	
Turnoff time	$t_{OFF}$	$V_{COM} = V_{CC}$ , $R_L = 50 \Omega$	$C_L = 35 \text{ pF}$ , See <a href="#">Figure 14</a>	25°C	2.5 V	17 27	ns
				Full	2.3 V to 2.7 V	30	
Break-before-make time	$t_{BBM}$	$V_{NC} = V_{NO} = V_{CC}$ , $R_L = 50 \Omega$	$C_L = 35 \text{ pF}$ , See <a href="#">Figure 15</a>	25°C	2.5 V	2 14 30	ns
				Full	2.3 V to 2.7 V	1 35	

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

## 6.10 Switching Characteristics for a 1.8-V Supply

 $V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$ ,  $T_A = -40^\circ\text{C to } 85^\circ\text{C}$  (unless otherwise noted) <sup>(1)</sup>

PARAMETER	TEST CONDITIONS	$T_A$	$V_{CC}$	MIN	TYP	MAX	UNIT
<b>Dynamic</b>							
Turnon time	$t_{ON}$	$V_{COM} = V_{CC}$ , $R_L = 50 \Omega$	$C_L = 35 \text{ pF}$ , See <a href="#">Figure 14</a>	25°C	1.8 V	53 75	ns
				Full	1.65 V to 1.96 V	80	
Turnoff time	$t_{OFF}$	$V_{COM} = V_{CC}$ , $R_L = 50 \Omega$	$C_L = 35 \text{ pF}$ , See <a href="#">Figure 14</a>	25°C	1.8 V	24 35	ns
				Full	1.65 V to 1.96 V	40	
Break-before-make time	$t_{BBM}$	$V_{NC} = V_{NO} = V_{CC}$ , $R_L = 50 \Omega$	$C_L = 35 \text{ pF}$ , See <a href="#">Figure 15</a>	25°C	1.8 V	2 30 40	ns
				Full	1.65 V to 1.96 V	1 50	

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

## 6.11 Typical Characteristics

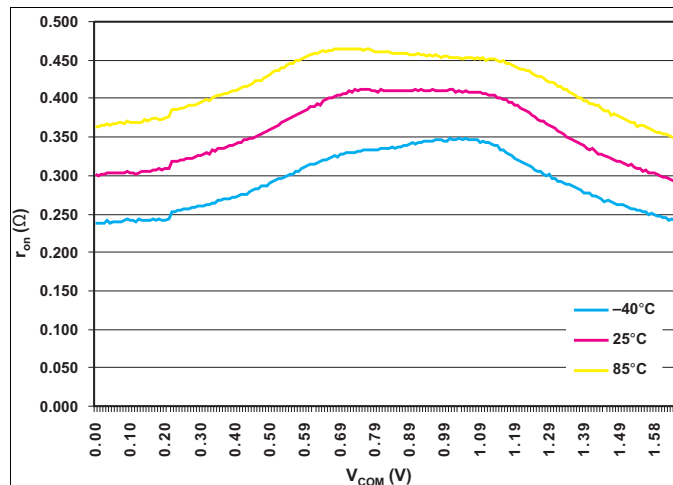


Figure 1.  $r_{on}$  vs  $V_{COM}$   
( $V_{CC} = 1.65$  V)

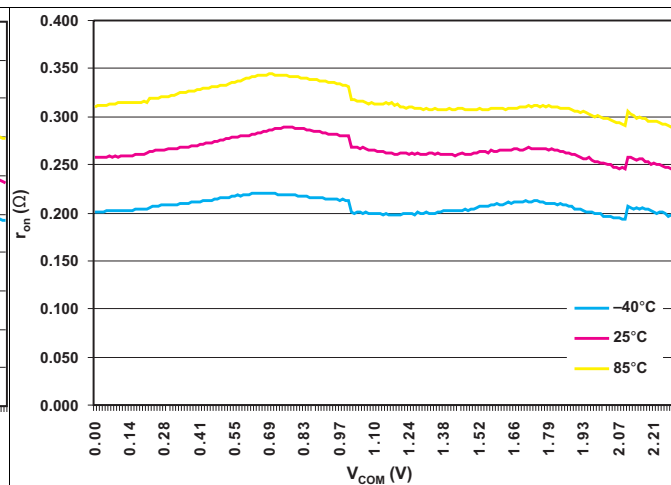


Figure 2.  $r_{on}$  vs  $V_{COM}$   
( $V_{CC} = 2.3$  V)

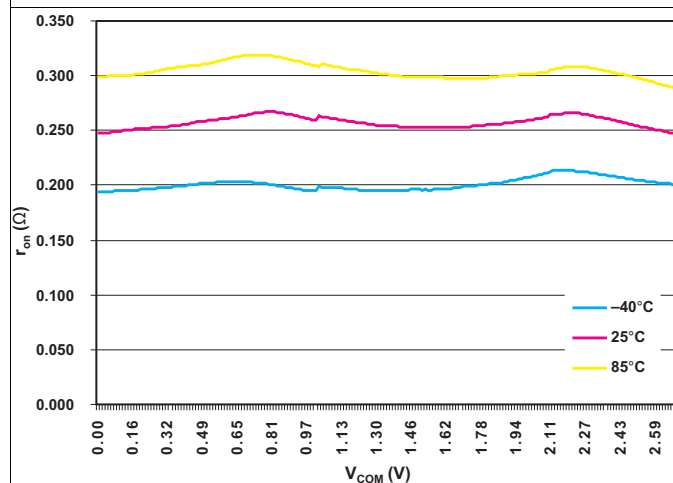


Figure 3.  $r_{on}$  vs  $V_{COM}$   
( $V_{CC} = 2.7$  V)

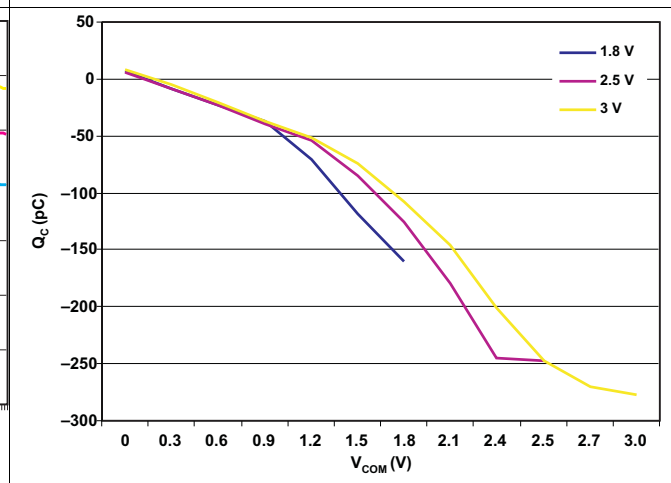


Figure 4. Charge Injection ( $Q_C$ ) vs  $V_{COM}$   
( $T_A = 25^\circ\text{C}$ )

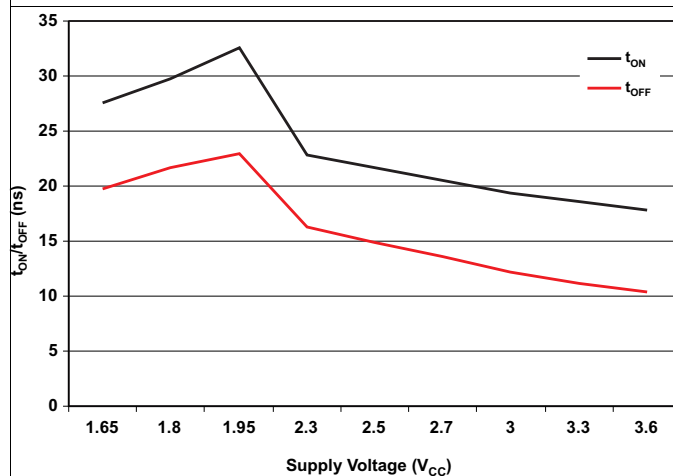


Figure 5.  $t_{ON}$  and  $t_{OFF}$  vs Supply Voltage  
( $T_A = 25^\circ\text{C}$ )

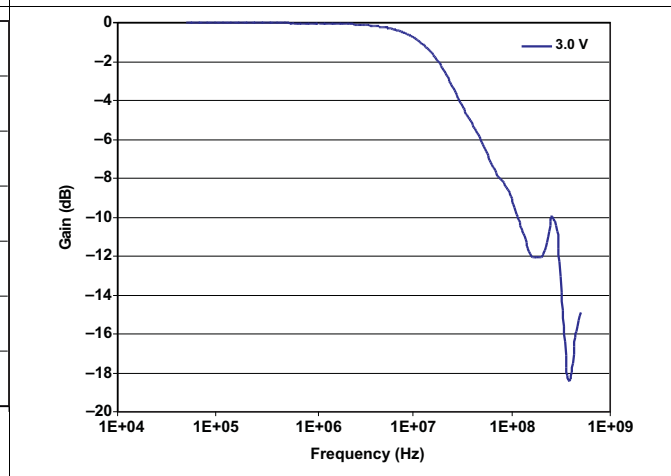
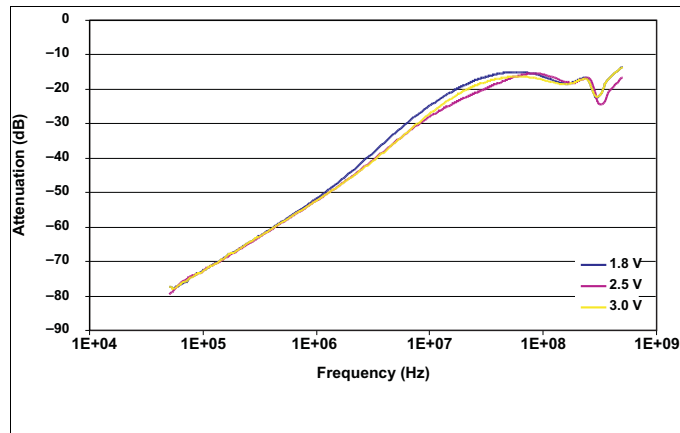
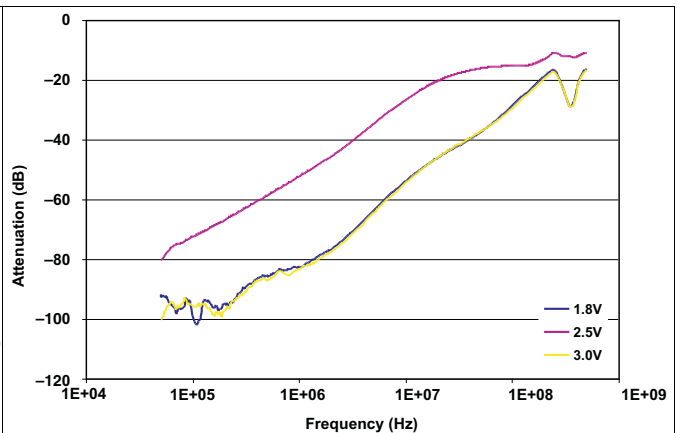


Figure 6. Bandwidth

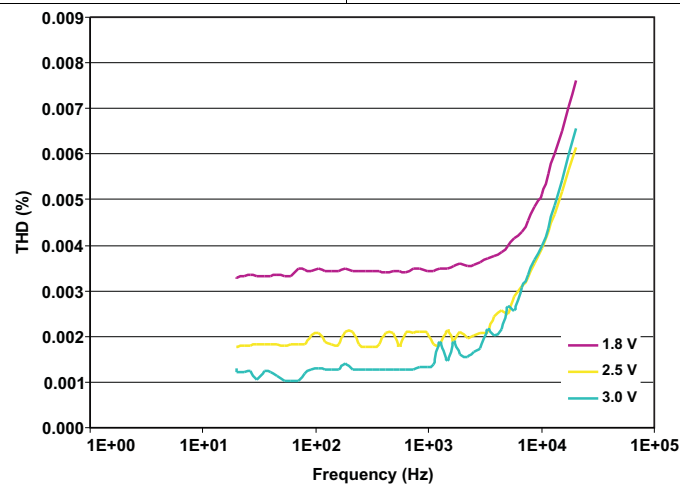
## Typical Characteristics (continued)



**Figure 7. OFF Isolation**

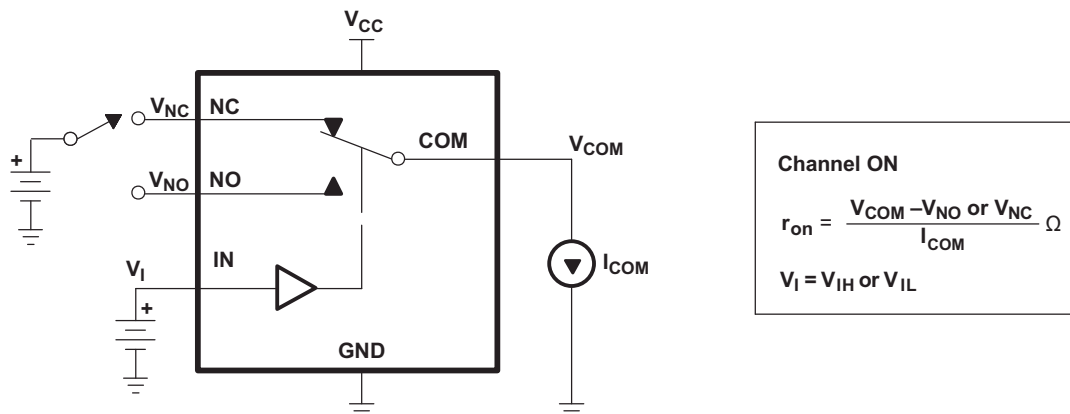


**Figure 8. Crosstalk**

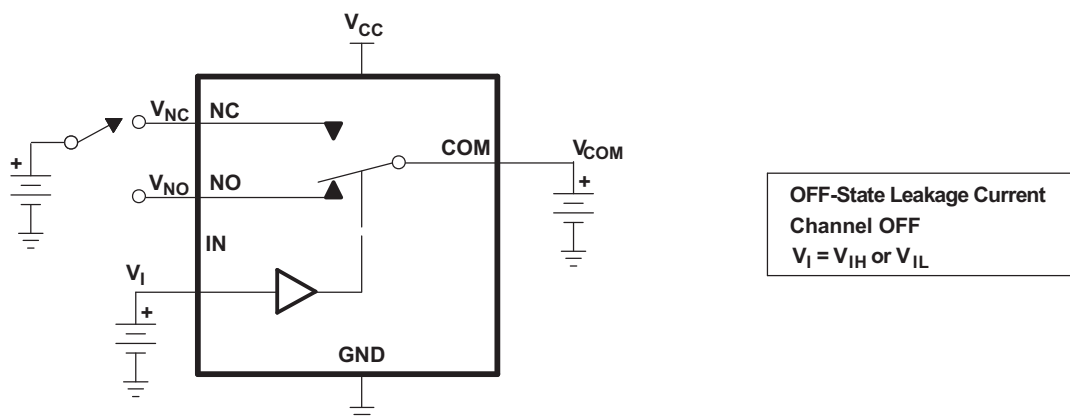


**Figure 9. Total Harmonic Distortion vs Frequency**

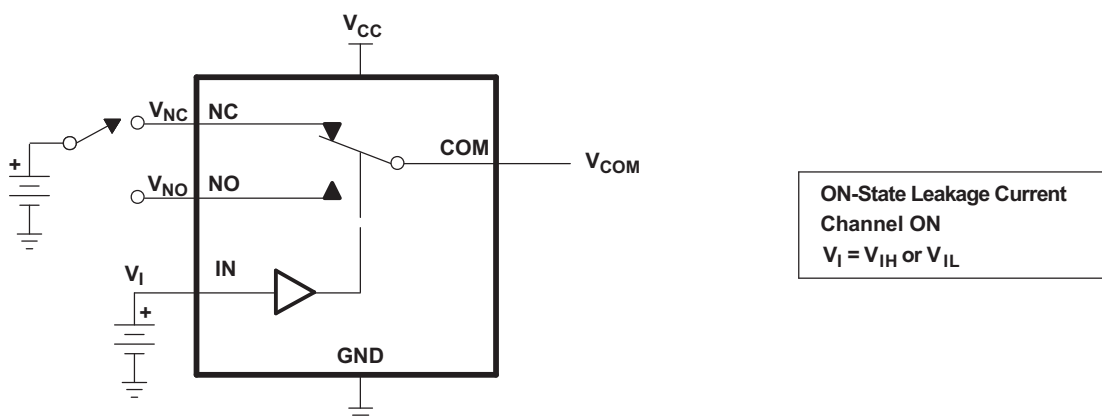
## 7 Parameter Measurement Information



**Figure 10. ON-State Resistance**



**Figure 11. OFF-State Leakage Current**  
( $I_{NC(OFF)}$ ,  $I_{NC(PWROFF)}$ ,  $I_{NO(OFF)}$ ,  $I_{NO(PWROFF)}$ ,  $I_{COM(OFF)}$ ,  $I_{COM(PWROFF)}$ )



**Figure 12. ON-State Leakage Current ( $I_{COM(ON)}$ ,  $I_{NC(ON)}$ ,  $I_{NO(ON)}$ )**

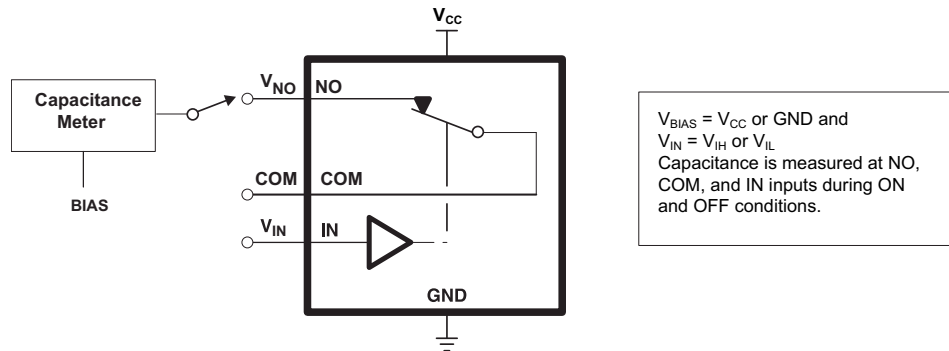
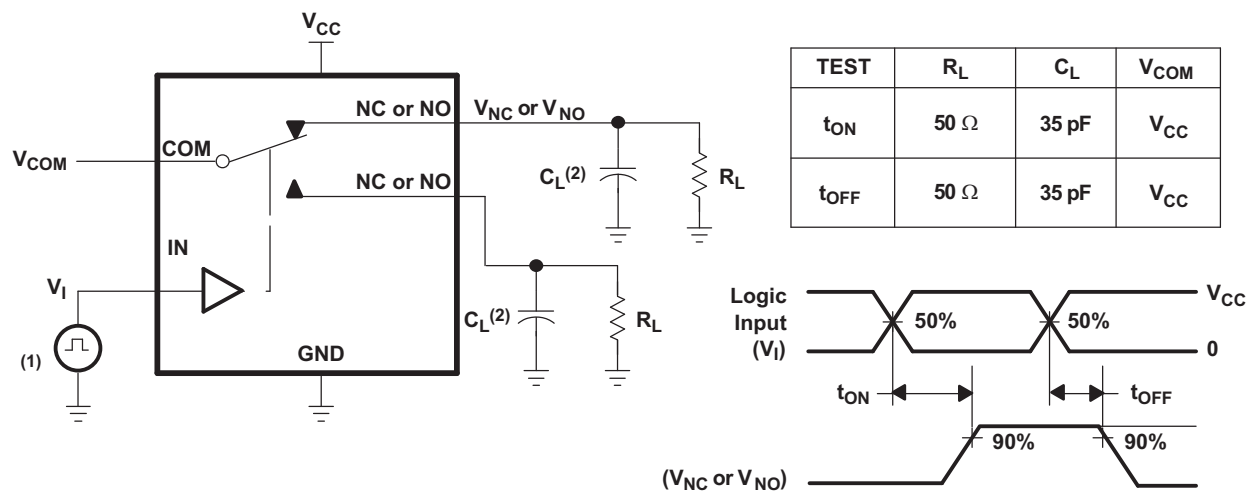
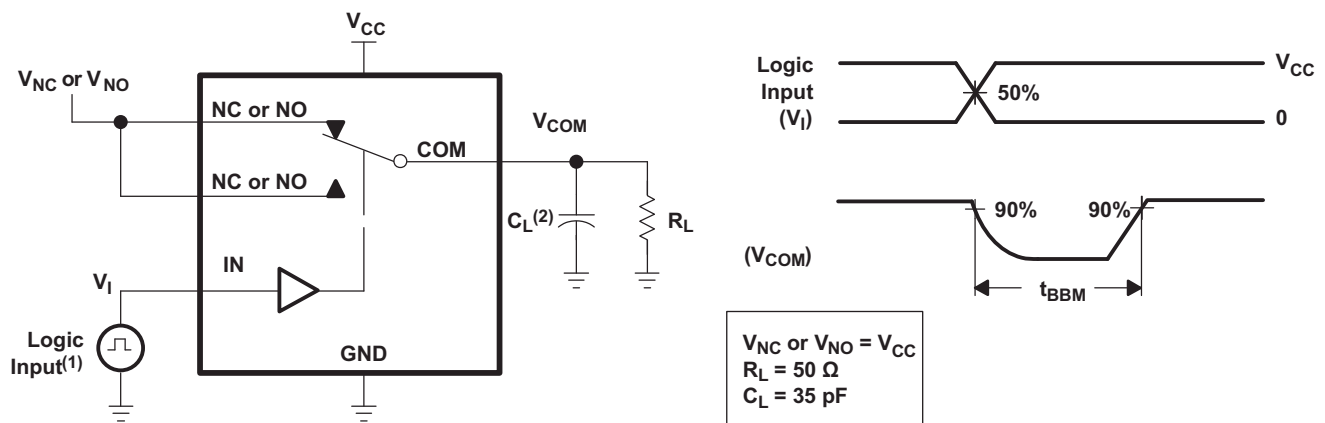


Figure 13. Capacitance  $C_I$ ,  $C_{NC(OFF)}$ ,  $C_{NO(OFF)}$ ,  $C_{NC(ON)}$ ,  $C_{NO(ON)}$



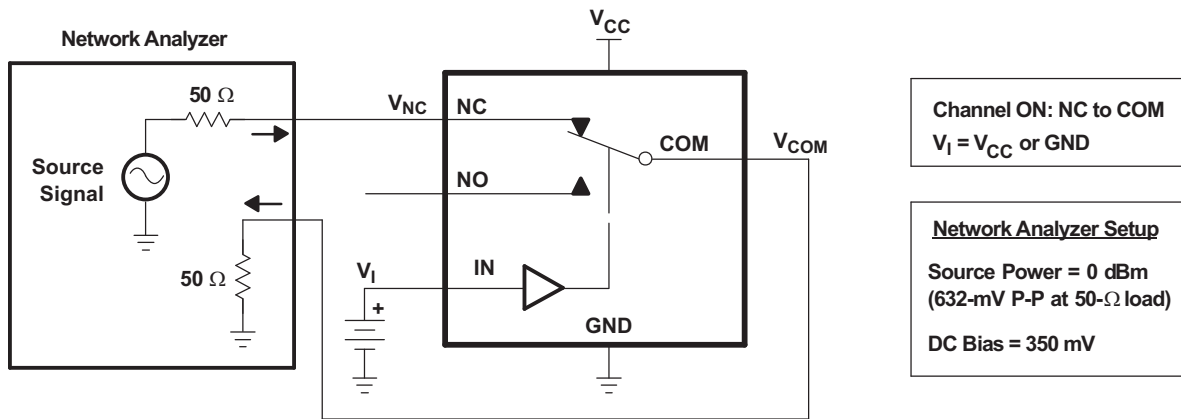
- (1) All input pulses are supplied by generators having the following characteristics:  $PRR \leq 10\ \text{MHz}$ ,  $Z_O = 50\ \Omega$ ,  $t_r < 5\ \text{ns}$ ,  $t_f < 5\ \text{ns}$ .
- (2)  $C_L$  includes probe and jig capacitance.

Figure 14. Turn-On ( $t_{ON}$ ) and Turn-Off Time ( $t_{OFF}$ )

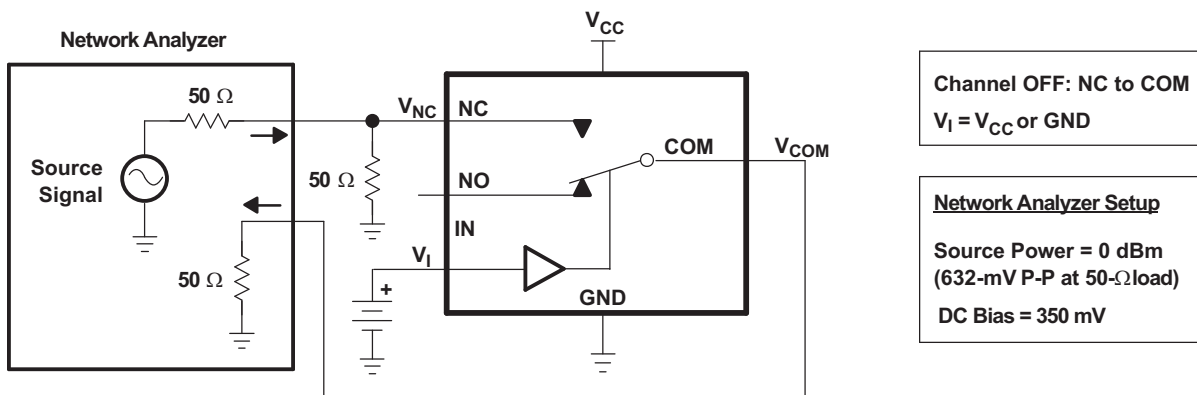


- (1) All input pulses are supplied by generators having the following characteristics:  $PRR \leq 10\ \text{MHz}$ ,  $Z_O = 50\ \Omega$ ,  $t_r < 5\ \text{ns}$ ,  $t_f < 5\ \text{ns}$ .
- (2)  $C_L$  includes probe and jig capacitance.

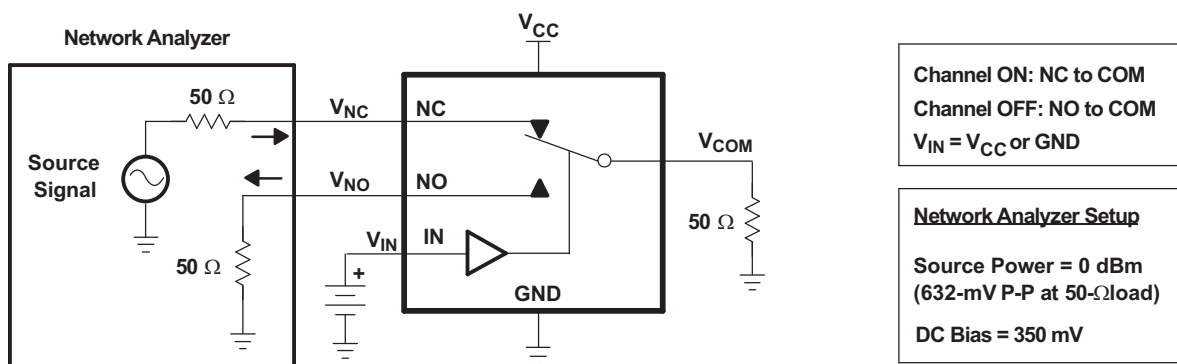
Figure 15. Break-Before-Make Time ( $t_{BBM}$ )



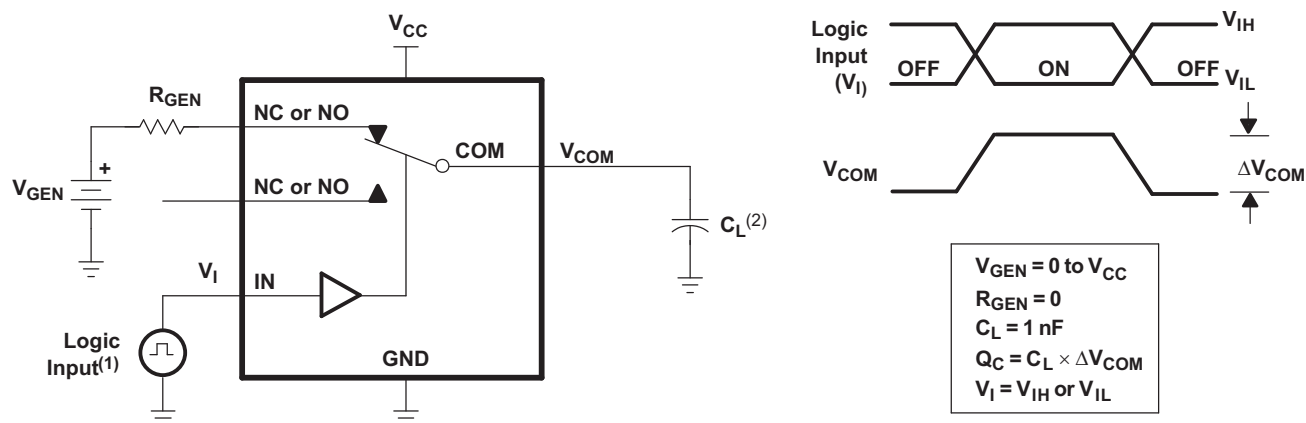
**Figure 16. Bandwidth (BW)**



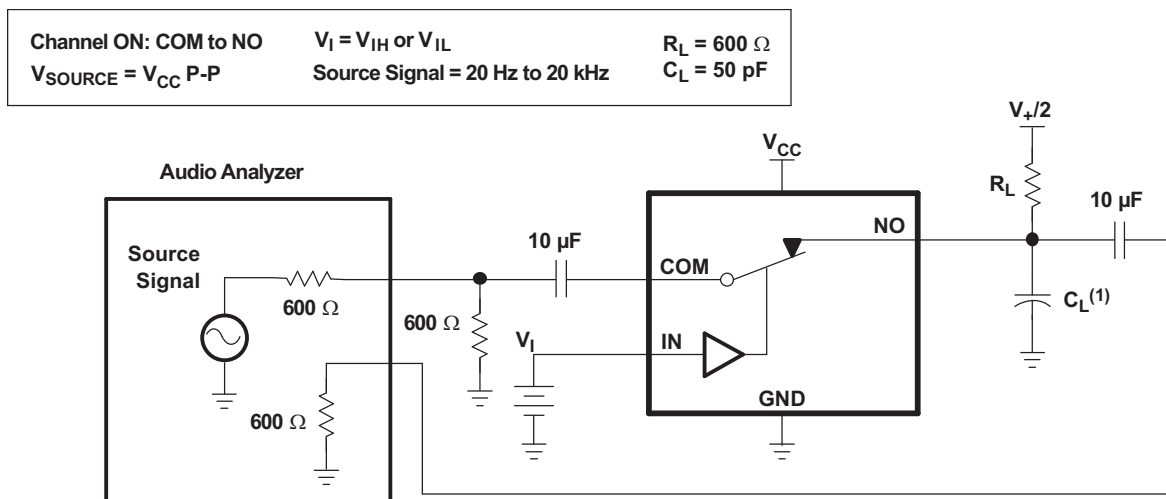
**Figure 17. OFF Isolation ( $O_{ISO}$ )**



**Figure 18. Crosstalk ( $X_{TALK}$ )**



- A. All input pulses are supplied by generators having the following characteristics:  $PRR \leq 10 \text{ MHz}$ ,  $Z_O = 50 \Omega$ ,  $t_r < 5 \text{ ns}$ ,  $t_f < 5 \text{ ns}$ .
- B.  $C_L$  includes probe and jig capacitance.

**Figure 19. Charge Injection ( $Q_C$ )**


- A.  $C_L$  includes probe and jig capacitance.

**Figure 20. Total Harmonic Distortion (THD)**

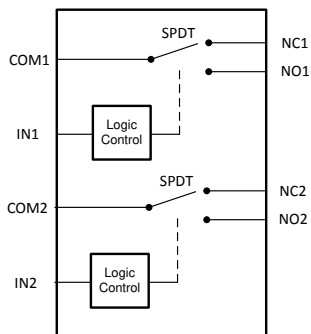


## 8 Detailed Description

### 8.1 Overview

The TS3A24159 is a 2-channel single-pole double-throw (SPDT) bidirectional analog switch that is designed to operate from 1.65 V to 3.6 V. It offers low ON-state resistance and excellent ON-state resistance matching with the break-before-make feature, to prevent signal distortion during the transferring of a signal from one channel to another. The device has excellent total harmonic distortion (THD) performance, low ON-state resistance, and consumes very low power. These are some of the features make this device suitable for a variety of markets and many different applications.

### 8.2 Functional Block Diagram



### 8.3 Feature Description

The TS3A24159 device is bidirectional with two single-pole, double-throw switches. Each of the two switches are controlled independently by two digital signals.

### 8.4 Device Functional Modes

**Table 1. Function Table**

IN	NC TO COM, COM TO NC	NO TO COM, COM TO NO
L	ON	OFF
H	OFF	ON

## 9 Application and Implementation

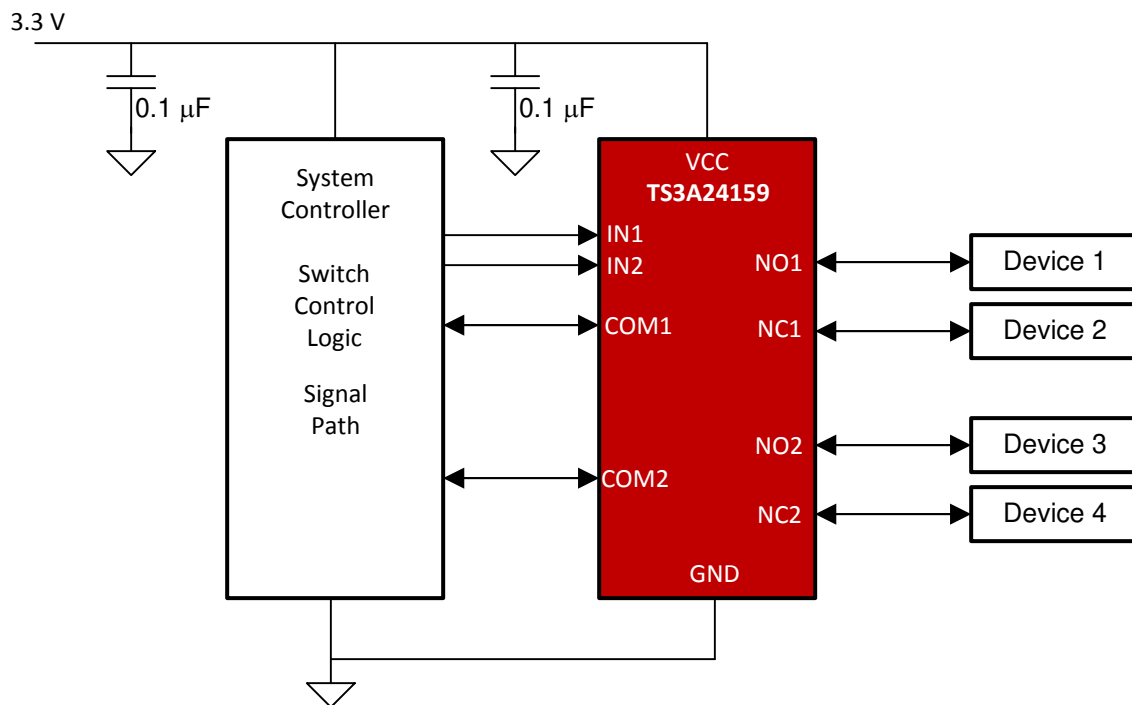
### NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

### 9.1 Application Information

The switch of the TS3A23159 device is bidirectional. Hence, NO, NC and COM pins can be used as both inputs or outputs.

### 9.2 Typical Application



#### 9.2.1 Design Requirements

Ensure that all of the signals passing through the switch are within the specified ranges to ensure proper performance.

**Table 2. Design Parameters**

		MIN	MAX	UNIT
$V_{CC}$	Supply Voltage	1.65	3.6	V
$V_{NC}$ $V_{NO}$ $V_{COM}$	Signal Voltage	0	$V_{CC}$	V
$V_{IN}$	Digital Input Voltage	0	$V_{CC}$	V

## 9.2.2 Detailed Design Procedure

The TS3A23159 device can be properly operated without any external components. However, it is recommended that unused pins must be connected to ground through a 50-Ω resistor to prevent signal reflections back into the device. It is also recommended that the digital control pins (IN1 and IN2) be pulled up to VCC or down to GND to avoid undesired switch positions that could result from the floating pin.

Select the appropriate supply voltage to cover the entire voltage swing of the signal passing through the switch because the TS3A23159 input/output signal swing through NO and COM are dependant of the supply voltage VCC.

## 9.2.3 Application Curve

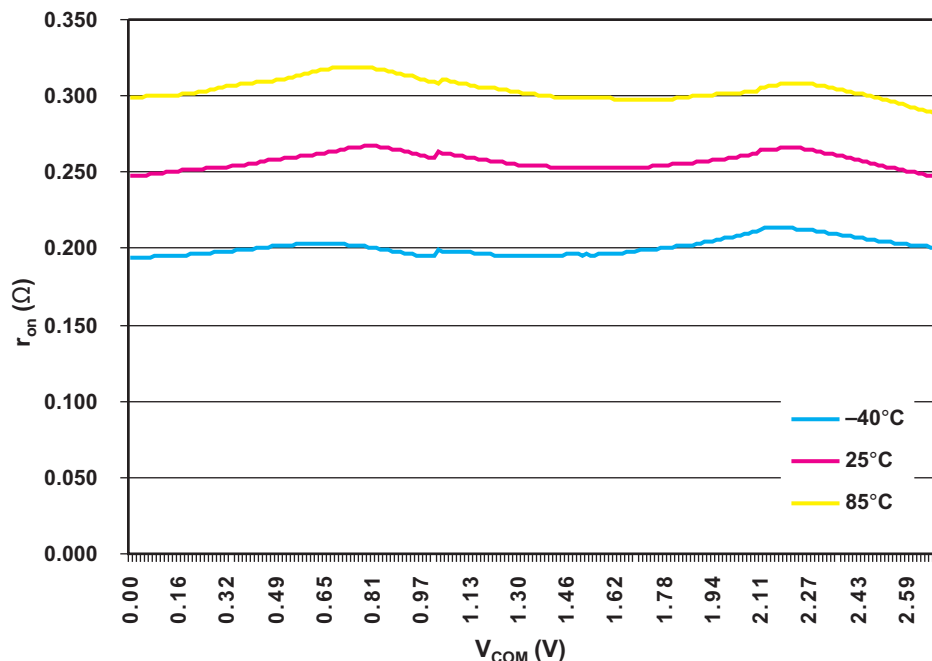


Figure 21.  $r_{ON}$  vs  $V_{COM}$

## 10 Power Supply Recommendations

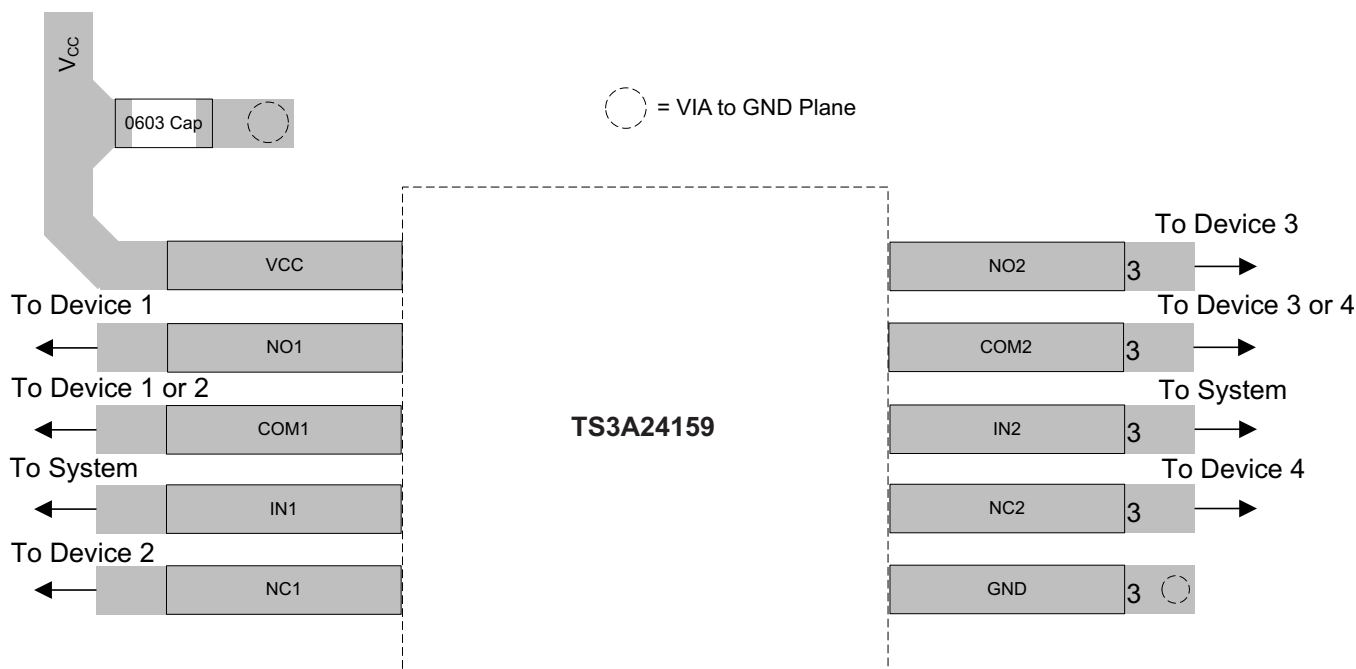
- Proper power-supply sequencing is recommended for all CMOS devices.
- Do not exceed the absolute maximum ratings, because stresses beyond the listed ratings can cause permanent damage to the device.
- Always sequence VCC on first, followed by NO or COM.
- Although it is not required, power-supply bypassing improves noise margin and prevents switching noise propagation from the VCC supply to other components.
- A 0.1-μF capacitor, connected from VCC to GND, is adequate for most applications.

## 11 Layout

### 11.1 Layout Guidelines

To ensure reliability of the device, following common printed-circuit board layout guidelines is recommended. Bypass capacitors must be used on power supplies. Short trace lengths should be used to avoid excessive loading.

### 11.2 Layout Example



**Figure 22. Layout Example**

## 12 Device and Documentation Support

### 12.1 Documentation Support

#### 12.1.1 Related Documentation

For related documentation see the following: *Implications of Slow or Floating CMOS Inputs*, [SCBA004](#)

### 12.2 Community Resources

[TI E2E™ support forums](#) are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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### 12.3 Trademarks

E2E is a trademark of Texas Instruments.

All other trademarks are the property of their respective owners.

### 12.4 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

### 12.5 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

## 13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

## PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TS3A24159DGSR	ACTIVE	VSSOP	DGS	10	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	(L8Q, L8R)	<a href="#">Samples</a>
TS3A24159DGSRG4	ACTIVE	VSSOP	DGS	10	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	(L8Q, L8R)	<a href="#">Samples</a>
TS3A24159DRCR	ACTIVE	VSON	DRC	10	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	ZWS	<a href="#">Samples</a>
TS3A24159DRCRG4	ACTIVE	VSON	DRC	10	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	ZWS	<a href="#">Samples</a>
TS3A24159YZPR	ACTIVE	DSBGA	YZP	10	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	L87	<a href="#">Samples</a>

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

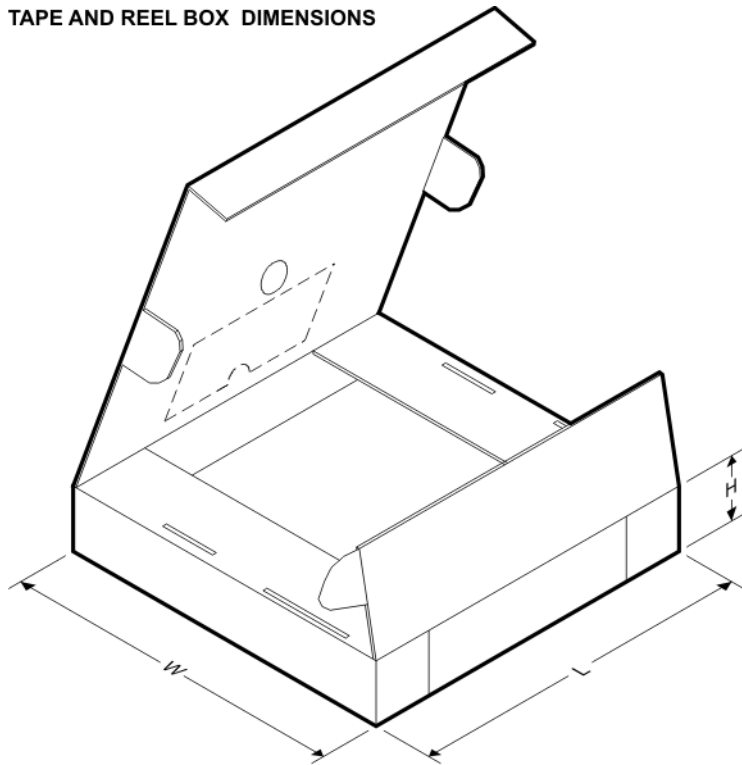
**TAPE AND REEL INFORMATION**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TS3A24159DGSR	VSSOP	DGS	10	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TS3A24159DRCR	VSON	DRC	10	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
TS3A24159YZPR	DSBGA	YZP	10	3000	178.0	9.2	1.49	1.99	0.63	4.0	8.0	Q2



## TAPE AND REEL BOX DIMENSIONS



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TS3A24159DGSR	VSSOP	DGS	10	2500	358.0	335.0	35.0
TS3A24159DRCR	VSON	DRC	10	3000	367.0	367.0	35.0
TS3A24159YZPR	DSBGA	YZP	10	3000	220.0	220.0	35.0

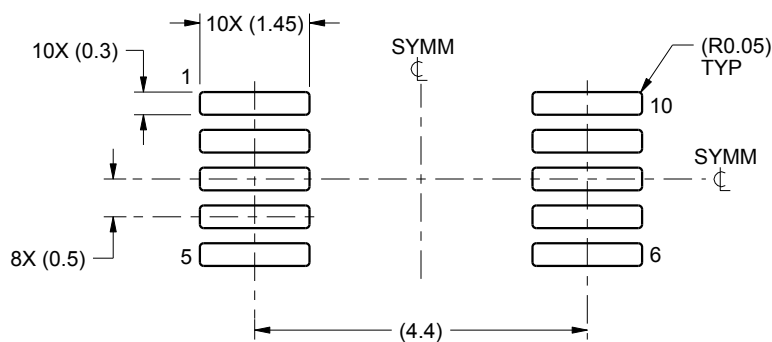


# EXAMPLE BOARD LAYOUT

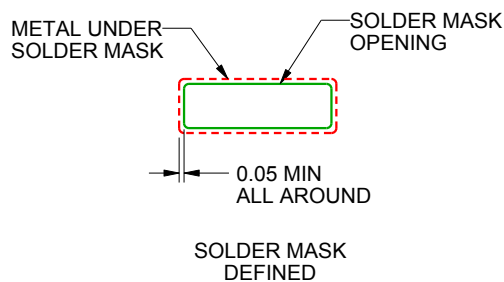
DGS0010A

VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE  
SCALE:10X



SOLDER MASK DETAILS  
NOT TO SCALE

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NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

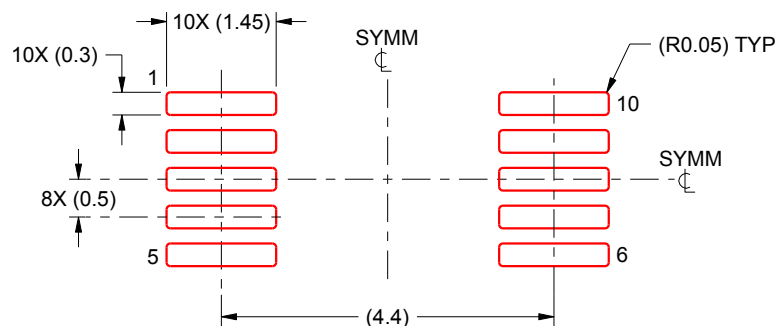
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

## EXAMPLE STENCIL DESIGN

DGS0010A

VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL  
SCALE:10X

4221984/A 05/2015

NOTES: (continued)

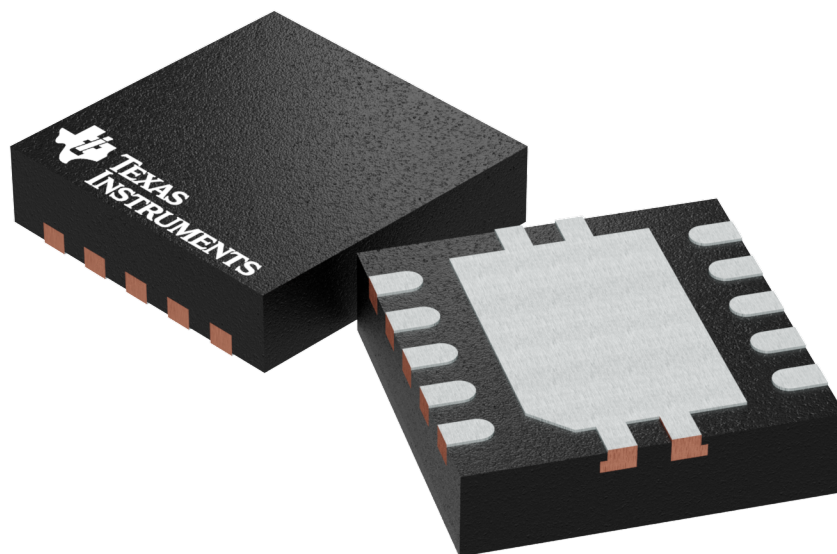
8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

## GENERIC PACKAGE VIEW

**DRC 10**

**VSON - 1 mm max height**

PLASTIC SMALL OUTLINE - NO LEAD



Images above are just a representation of the package family, actual package may vary.  
Refer to the product data sheet for package details.

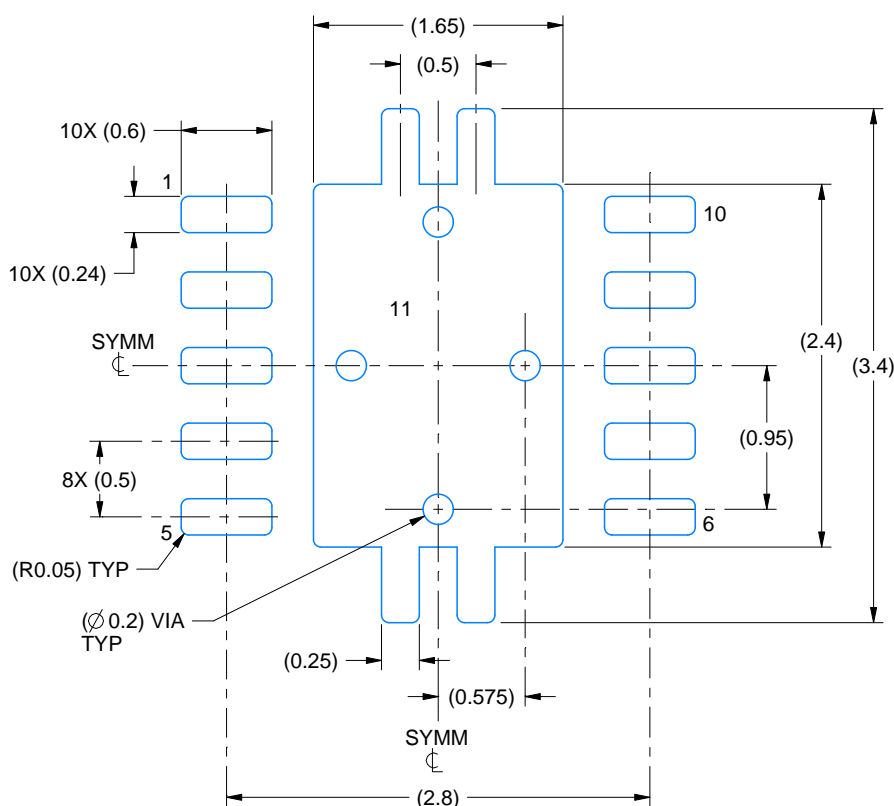
4204102-3/M



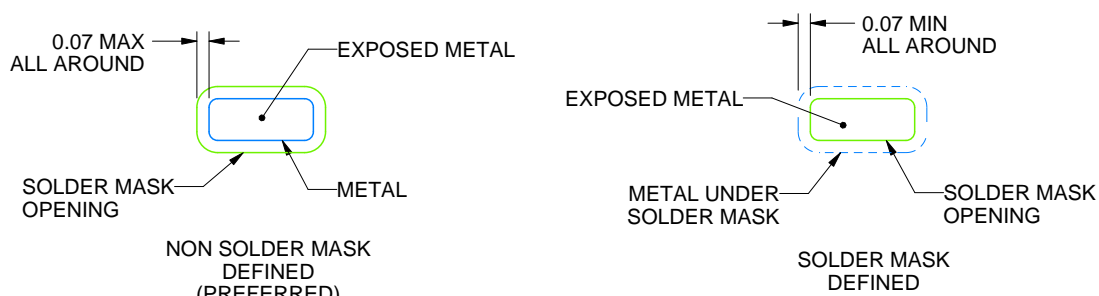
**DRC0010J**

**VSON - 1 mm max height**

PLASTIC SMALL OUTLINE - NO LEAD



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE:20X



## SOLDER MASK DETAILS

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NOTES: (continued)

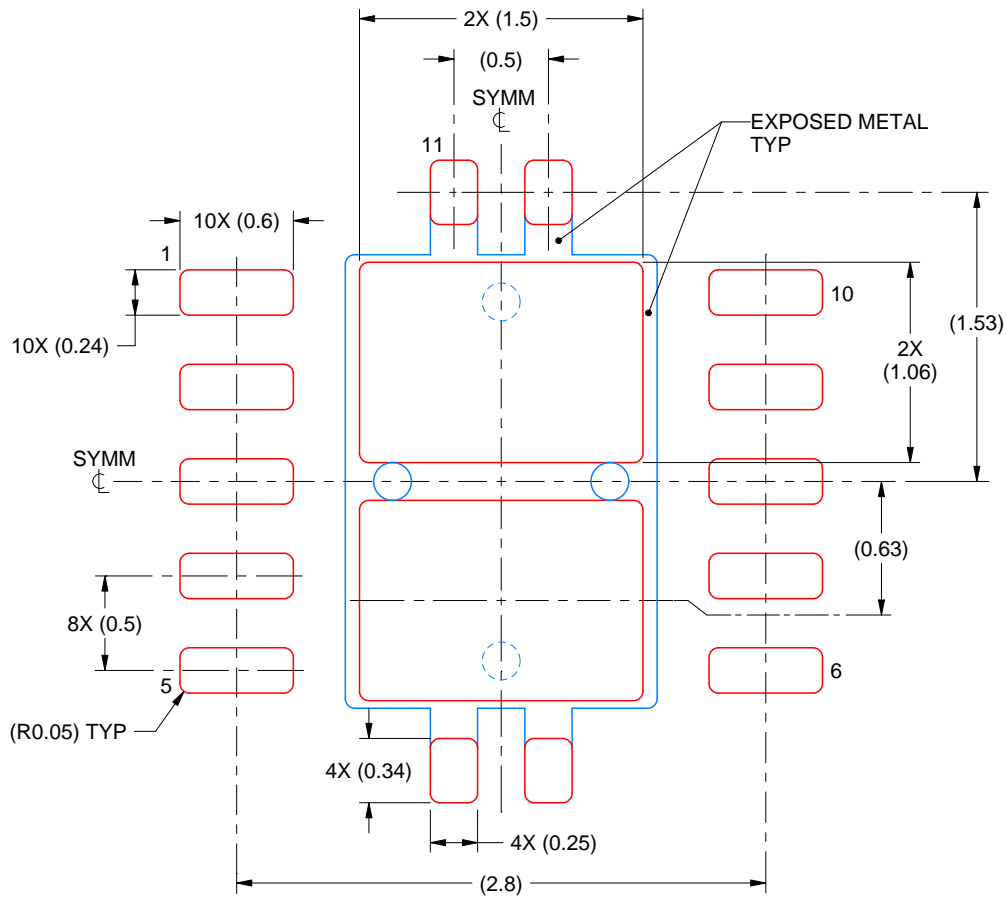
4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 ([www.ti.com/lit/slua271](http://www.ti.com/lit/slua271)).
5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

# EXAMPLE STENCIL DESIGN

DRC0010J

VSON - 1 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD 11:  
80% PRINTED SOLDER COVERAGE BY AREA  
SCALE:25X

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NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



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